Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-057-5956

| Inclosure Matarial | |
|---------------------------|-----------------------------------|
| Inclosure Material: | |
| Metal and glass | |
| Overall Length: | |
| 0.265 inches | |
| Terminal Length: | |
| 1.500 inches | |
| Overall Diameter: | |
| Between 0.210 inches a | |
| Function For Which D | esigned: |
| Detector | |
| Mounting Method: | |
| Terminal | |
| Terminal Circle Diame | ter: |
| 0.100 inches | |
| Features Provided: | |
| Gold plated leads | |
| Semiconductor Materi | al: |
| Silicon | |
| Voltage Rating In Volt | |
| 1.5 on voltage, forward | |
| Current Rating Per Ch | |
| - | urce cutoff current preset |
| Power Rating Per Cha | |
| 250.0 milliwatts total po | |
| | empurature Per Measurement Point: |
| 100.0 degrees celsius a | |
| Precious Material And | Location: |
| Terminal surfaces gold | |
| Precious Material: | |
| Gold | |
| Terminal Type And Qu | iantity: |
| 3 uninsulated wire lead | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |